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Electric-field-driven octahedral rotation in perovskite

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Rotation of MO_6 (M = transition metal) octahedra is a key determinant of the physical properties of perovskite materials. Therefore, tuning physical properties, one of the most important goals in condensed matter research, may be accomplished by controlling octahedral rotation (OR). In this study, it is demonstrated that OR can be driven by an electric field in Sr_2RuO_4 . Rotated octahedra in the surface layer of Sr_2RuO_4 are restored to the unrotated bulk structure upon dosing the surface with K. Theoretical investigation shows that OR in Sr_2RuO_4 originates from the surface electric field, which can be tuned via the screening effect of the overlaid K layer. This work establishes not only that variation in the OR angle can be induced by an electric field, but also provides a way to control OR, which is an important step toward in situ control of the physical properties of perovskite oxides.

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INTRODUCTION

Perovskite materials possess some of the most interesting properties in condensed matter physics, such as superconductivity, metal–insulator transitions, and ferroicity¹. Theoretical and experimental research has proven that octahedral rotation (OR) plays an important role in those properties. For instance, OR significantly affects metal–insulator transitions^{2,3} and exotic orbital-selective phenomena^{4,5} by changing the inter-site electron hopping probability and even the structural symmetry of materials. Furthermore, the magnetic ground state of a material is often governed by OR through altered super-exchange or Dzyaloshinskii–Moriya interactions⁶. Therefore, the ability to readily vary OR would be an important step toward controlling such physical properties.

However, in spite of its importance, there are a limited number of reports on controlling OR^{7–9}. The main reason for this is that the OR angle is thought to be an inherent characteristic of a material, determined by the steric effect arising from the sizes of its constituent atoms^{10,11}. Thus, most of the attempts to control OR have been limited to substitution of atoms with different ionic sizes or application of strains using different substrates. However, these methods do not truly allow control of the OR angle as they cannot be applied in situ, and typically cause complex side effects^{12,13}.

When attempting to control physical properties through the OR angle, various parameters should be considered, such as pressure and magnetic and electric fields. Among these parameters, the electric field has distinct advantages in terms of convenience, controllability, and minimal power consumption. In this letter, we report electric-field-dependent evolution of the OR angle on the surface of Sr_2RuO_4 . By means of in situ dosing with potassium (K), the surface electric field can be tuned through the screening effect of the overlying K atoms. Sr_2RuO_4 was chosen as the target material given its distinct surface layer-driven bands, which arise due to differences in its structural symmetry (a finite OR angle at its surface and no rotation of its bulk)^{14–16}; these properties not only provide clean surfaces, but also make investigation of its electronic structure relatively easy. Our results obtained using the

surface-sensitive techniques of low-energy electron diffraction (LEED) and angle-resolved photoelectron spectroscopy (ARPES) indicate that reduction of the electric field results in a reduced OR angle (down to zero). Our density functional theory (DFT) studies have shown that the surface electric potential (or surface electric field)^{17,18} is responsible for the OR on the surface of Sr_2RuO_4 , which in turn implies the possibility of controlling the OR angle via an electric field.

RESULTS

Disappearance of Sr_2RuO_4 surface states upon K coverage

Figure 1 shows Fermi surface (FS) maps of freshly cleaved and K-dosed Sr_2RuO_4 surfaces. The main features are two bulk electron pockets (β^b and γ^b) centered at Γ and a bulk hole pocket (α^b) centered at (π, π) . In addition to these bulk FSs, we detected additional FSs from the surface ($\alpha^s, \beta^s, \gamma^s$) and zone-folded surface ($\alpha^{sf}, \beta^{sf}, \gamma^{sf}$) bands (Fig. 1a), consistent with previously reported ARPES results^{15,16,19}. Notably, when we deposit K on the surface with coverage above one monolayer (ML), all of the surface-related FSs disappear (Fig. 1b), which is somewhat similar to the case of surface aging of Sr_2RuO_4 (refs. 16,19). To deduce the reason for this disappearance, we systematically varied the coverage of K while conducting LEED and ARPES measurements.

LEED is one of the most direct and convenient methods to investigate in-plane crystal symmetry. In case when there is no OR distortion, only the 1×1 peak should appear. When the in-plane OR angle is finite, the unit cell is transformed to a $(\sqrt{2} \times \sqrt{2})R45^\circ$ unit cell, and consequently additional fractional peaks ($\sqrt{2} \times \sqrt{2}$) should appear in the LEED pattern. The relative intensity of the fractional to integer spot is approximately proportional to the OR angle^{20,21}. The LEED results from our systematic investigation of K coverage are shown in Fig. 2a. In the LEED data of pristine Sr_2RuO_4 , we can observe both 1×1 and $\sqrt{2} \times \sqrt{2}$ peaks. As the K coverage increases, the OR-driven $\sqrt{2} \times \sqrt{2}$ peaks gradually weaken and eventually disappear above 1 ML of K, while the 1×1 peaks remain robust. Therefore, we suspect that the K layer

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gradually and eventually completely suppresses the OR of the surface Sr_2RuO_4 .

The ARPES results from our systematic investigation of K coverage are shown in Fig. 2b; they also provide evidence for the suppression of OR in the surface Sr_2RuO_4 . The data for pristine Sr_2RuO_4 along Γ -M- Γ (Fig. 2b) show β^b , β^s , γ^b , and γ^s bands. As the K coverage increases, the β^s band, instead of being suppressed,

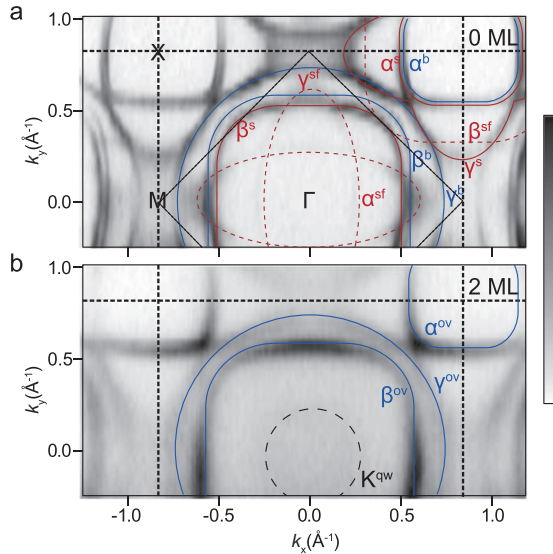


Fig. 1 Fermi surface (FS) maps of Sr_2RuO_4 . **a** Fresh Sr_2RuO_4 and **b** Sr_2RuO_4 covered in two monolayers (MLs) of K. The black thick (thin) dashed lines mark the Brillouin zone of the bulk (surface) Sr_2RuO_4 without (with) octahedral rotation. RuO_6 octahedra on the surface rotate, resulting in a $\sqrt{2} \times \sqrt{2}$ reconstructed surface that causes replica FSs to appear. Superscripts b, s, sf, and ov denote bulk, surface, surface folding, and overlap, respectively. The blue (red) guidelines indicate the bulk (surface) bands. K^{qw} indicates a K circular quantum well state (Supplementary Fig. 4).

moves toward β^b before finally merging with it. As for the γ bands, γ^b remains the same while the spectral weight of the γ^s band at the M-point gradually weakens. These observations indicate that the difference between the bulk and surface electronic structures gradually decreased, consistent with the suppression of OR in the surface layer. Our detailed analysis regarding the ARPES spectra (Supplementary Fig. 1) also supports that the suppression of the surface layer-driven bands is induced by suppression of the surface OR.

Cause of the suppressed OR

The next question is why the OR angle reduces with K-dosing. Surface alkali metal atoms can play roles in electron doping, chemical bonding, and changing the surface electric potential; we shall consider each in turn. First, we consider the possibility that the vanishing OR is caused by electron transfer from the alkali metal to the Sr_2RuO_4 . To investigate this, we obtained the electron occupations of the bands from their FS volume; we list these in the Supplementary Table 1 along with all other values discussed here. We find that there is an occupation difference of 0.09 electrons between the fresh surface (3.82) and that with 1 ML of K (3.91), which agrees well with the number (0.07) extracted from our theoretical study (Supplementary Fig. 2). However, an average transfer of 0.09 electrons from the K atoms is not likely to cause complete suppression of OR considering the case of $(\text{Sr},\text{La})_2\text{RuO}_4$, which is regarded as electron-doped Sr_2RuO_4 (Supplementary Fig. 3). On the other hand, effects arising from chemical bonding cannot provide an adequate explanation either; our measured K 3p core-level spectra as a function of K coverage (Supplementary Fig. 4) clearly show the absence of chemical bonding associated with K atoms. Furthermore, as mentioned, our experimental and theoretical results (Supplementary Table 1 and Supplementary Fig. 2) suggest that there is an electron transfer of only 0.07–0.09 from the K atoms, which is too small to be due to chemical bonding between the K and O atoms.

As the change in OR angle cannot be attributed to electron doping or chemical bonding effects, let us now consider the gradient of the surface electric potential. In general, the electric potential is modulated due to the electric potential difference

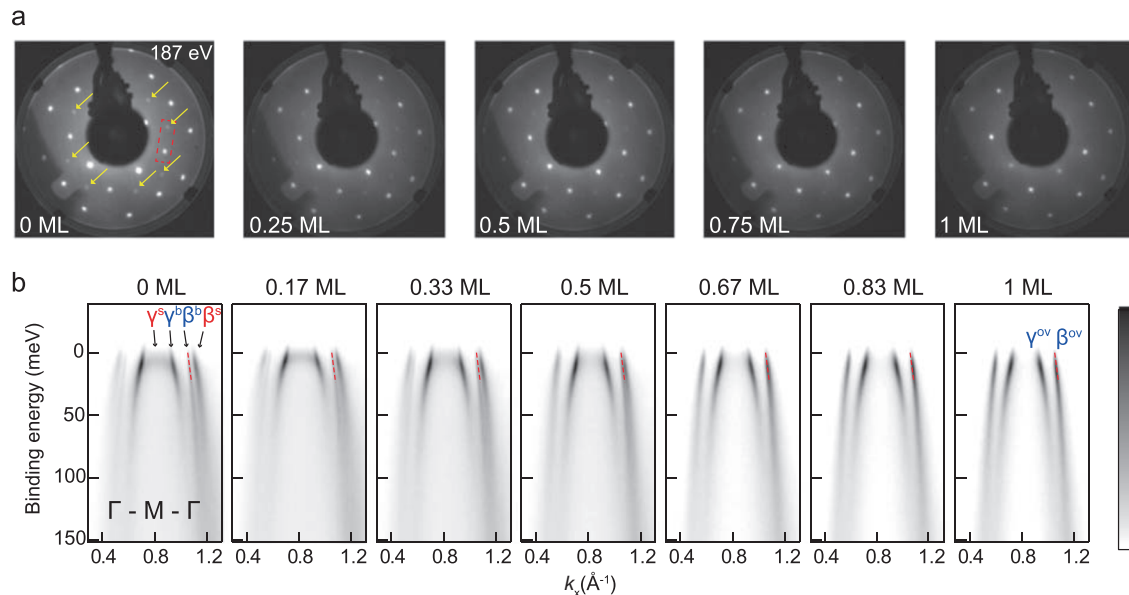


Fig. 2 Low-energy electron diffraction and angle-resolved photoelectron spectroscopy results according to the K coverage. **a** Electron diffraction images for various K coverages (0, 0.25, 0.5, 0.75, and 1 ML). The yellow arrows indicate peaks due to $\sqrt{2} \times \sqrt{2}$ surface reconstruction; as the K coverage increases, these peaks gradually become weaker and eventually disappear. The rectangle in red is the region of quantitative intensity analysis in Supplementary Fig. 1. **b** Photoelectron spectroscopy images along Γ -M- Γ for various K coverages (0, 0.17, 0.34, 0.5, 0.67, 0.83, and 1 ML). Red dashed lines are to mark the position of β^b of 0 ML coverage.

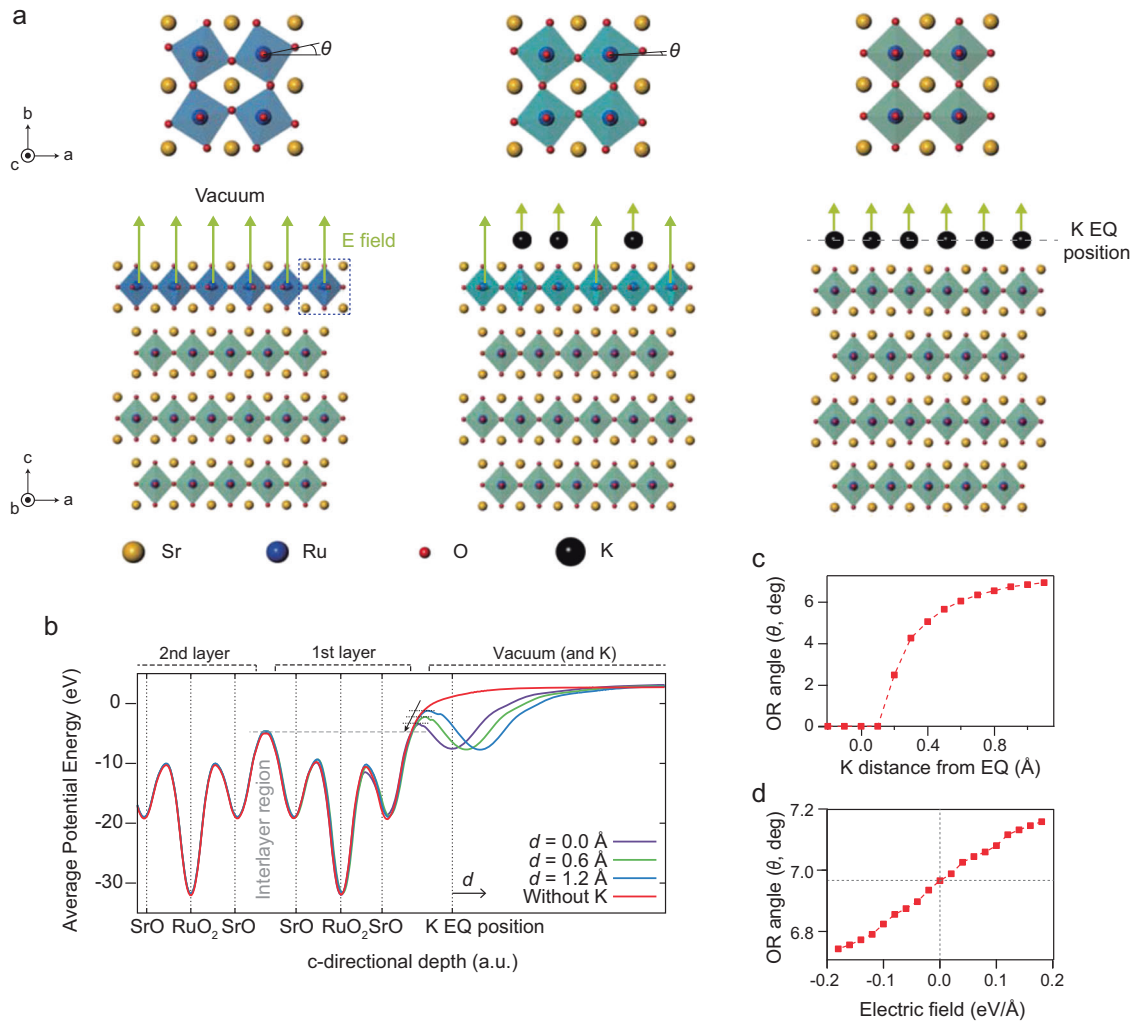


Fig. 3 Electric-potential-driven octahedral rotation (OR). **a** Crystal structure of Sr₂RuO₄ with three different K coverages (left: fresh, middle: partial coverage, right: 1 ML). The dashed rectangle marks the area for the enlarged view in Fig. 4a. **b–d** Density functional theory (DFT) results for a slab of Sr₂RuO₄ five layers thick. **b** Electric potential energy as a function of the depth in the c -direction (surface normal), for various K-layer distances from the equilibrium position: $d = 0.0, 0.6, 1.2$ Å and without a K layer. The equilibrium position of the surface K layer (9.4 Å from the second outermost Ru–O layer) was obtained from the DFT calculation. The gray horizontal dashed line indicates the electric potential energy in the Sr₂RuO₄ interlayer region. As the K-layer distance decreases, the electric potential in the Sr–K region gradually decreases toward the value of the interlayer region (black arrow). **c** Plot of OR angle as a function of the K-layer distance from the equilibrium position. **d** Plot of OR angle as a function of electric field.

between vacuum and solid. This electric potential modulation is greatly affected by the surface condition, as illustrated in Fig. 3a and b. To investigate how electric potential relates to the OR angle, we performed a DFT calculation which has been widely used to describe low-energy physics in Sr₂RuO₄ (refs. ^{15,16,22}), by constructing a five-layer slab of Sr₂RuO₄ with and without an ML of K overlaid. We also performed calculations for various K-layer distances away from the equilibrium position, to investigate the evolution of the electric potential and OR angle.

First, we note that the potential energy decreases gradually toward the value of the interlayer region as the K layer approaches the equilibrium position (the arrow in Fig. 3b). This suggests that the role of the K layer is to mitigate the surface electric field; 1 ML of K causes the electric potential in the surface region to become similar to the interlayer potential. Consequently, the surface layer is in a bulk-like potential, which should lead to the suppression of OR (Fig. 3a). The calculated OR angle monotonically evolves from zero to fully rotated as the K-layer distance increases from the equilibrium position (Fig. 3c). These observations strongly indicate

that the origin of the OR is in the electric field, consistent with the experimental data in Fig. 2.

Even though it is not essential to prove the electric origin of the OR, it is noteworthy that the OR evolution in the calculation in Fig. 3c fairly consistently reproduces the behavior according to the thickness of the K layer seen in the experimental data. Partial K-coverage cases have been simulated by artificially moving the K layer away from the equilibrium position²³. The similarity between the experimental and theoretical results may be understood in the following way. Figure 3b shows the calculated electric potential as a function of the K-layer distance from surface layer. The electric potential at the interface (between the outermost SrO layer and the K layer) monotonically and gradually changes as the K-layer distance changes. We expect that the surface electric field will be screened by K atoms proportionally with the K coverage (Fig. 3a). Therefore, the ‘moving K-layer distance’ should generate similar trends in the electric potential as does the K coverage. Our electronic structure with ‘moving K-layer distance’ does indeed show trends consistent with our K-coverage-dependent ARPES

results (Supplementary Fig. 5); hence, the method should be reasonable to observe the overall trend.

To directly investigate the role of the electric field in the OR angle, we performed another five-layer slab calculation, this time with an external electric field applied perpendicular to the surface (Fig. 3d). Our DFT calculations of total energy predict that the surface OR changes, exhibiting behavior proportional to the increase of $\sim 0.15^\circ$ per 0.1 V \AA^{-1} (Fig. 3d); thus, the electric field appears to be coupled to the OR. Therefore, we conclude that the electric field is responsible for the OR in the Sr_2RuO_4 surface layer and thus the OR can be varied by tuning the electric potential.

Mechanism of the electric-field-driven OR

The next step is to find out how an electric field couples with the OR. Previous theoretical studies have shown that ferroelectric-like atomic displacement competes with the OR, which is the reason why most of ferroelectric materials do not have OR distortion²⁴. Therefore, it is natural to consider non-uniform atomic displacements driven by depth-dependent electric field as the cause for the OR angle change. From our DFT calculation with K-layer distance variation, we extract atomic displacement in the outermost Sr–O layer. It shows that the distance between upper and lower Sr atoms in the surface Sr_2RuO_4 layer is the most sensitive factor to the K-layer distance (Supplementary Fig. 6). It is found that the vertical Sr–Sr distance (defined in Fig. 3a) increases with the electric field (K-layer distance) and changes more than 0.1 \AA as shown in Fig. 4a.

In order to check whether the (vertical) Sr–Sr distance is coupled to the OR angle variation, we have estimated OR angle from bulk Sr_2RuO_4 calculation as a function of the Sr–Sr distance (Fig. 4b). As can be seen in Fig. 4b, variation of the Sr–Sr distance successfully reproduces emergence of the OR angle in Sr_2RuO_4 in the range over which the Sr–Sr distance varies in Fig. 4a. Therefore, it appears that the Sr–Sr distance is the mediating parameter between the surface electric field and OR angle. As the stronger (weaker) surface electric field makes a larger (smaller) Sr–Sr distance, and it eventually leads to a larger (smaller) OR angle. In this context, we can reconsider how OR varies depending on the situation in Sr_2RuO_4 . Absence of surface electric potential makes octahedron unrotated in bulk Sr_2RuO_4 . On the other hand, the surface layer feels the surface electric potential, and thus the (surface electric potential driven) large Sr–Sr distance makes octahedron rotated in the surface layer. Upon K dosing, the K atoms gradually reduce the surface electric potential toward the value of bulk electric potential. Then, the OR angle in the surface layer gradually decreases down to zero as we observed.

This mechanism can be applied to various materials other than Sr_2RuO_4 . We performed additional bulk calculation on Sr_2RhO_4

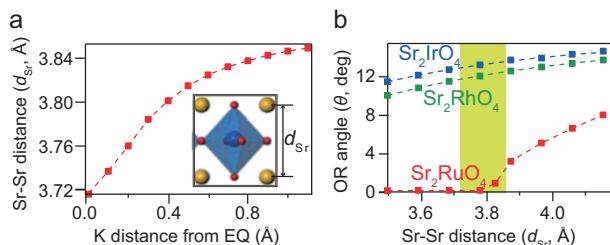


Fig. 4 Vertical Sr–Sr distance as the link between the surface electric potential and OR angle. **a** DFT calculation results from a five- Sr_2RuO_4 -layer slab. The plot shows the Sr–Sr distance as a function of the K-layer distance. Inset: enlarged view of an octahedron in the surface Sr_2RuO_4 layer. Sr–Sr distance (d_{Sr}) is defined as the vertical distance between upper and lower Sr atoms. **b** DFT results for the OR angle as a function of the Sr–Sr distance for bulk Sr_2RuO_4 , Sr_2RhO_4 , and Sr_2IrO_4 . The shaded region marks the actual range over which the Sr–Sr distance varies in **a**.

and Sr_2IrO_4 for various Sr–Sr distances (Fig. 4b), and it is found that OR angles of Sr_2RhO_4 and Sr_2IrO_4 are affected by Sr–Sr distance in the same manner as in the case of Sr_2RuO_4 , even though the large initial OR angles of Sr_2RhO_4 and Sr_2IrO_4 make their variation less dramatic. These results not only consistently simulate the OR angle variation behavior in K-dosed Sr_2RuO_4 , but also suggest that there might be universal coupling between the OR angle and cation distance in transition-metal oxide (TMO).

DISCUSSION

We shall now discuss the difference between the local and external electric fields to allow our result to be more fully understood. Even though we theoretically demonstrated an OR angle change by an external electric field (Fig. 3d), $\sim 4 \text{ V \AA}^{-1}$ is required for full suppression of the OR, which is not practical. However, a local electric field (potential gradient near the surface) can induce full suppression of the OR in Sr_2RuO_4 , as shown in Fig. 3b, where varying the K-layer distance changes the electric potential energy on the order of a few eV. This case demonstrates the advantages of exploiting the local electric field, in terms of strength and controllability. In practice, such local electric fields could be achieved by using special techniques such as ionic gating or even exploiting existing, naturally occurring fields at interfaces. In that respect, issues in groups of material heterostructures, which exhibit numerous exotic phenomena that the corresponding bulk crystals do not, such as superconductivity^{25,26}, metal–insulator transitions²⁷, and controllable ferromagnetism could be revisited²⁸. We suspect that local electric fields at interfaces play a significant role in generating these phenomena, and our findings should provide important clues regarding their microscopic mechanisms.

Since OR is not a polar distortion, whereas an electric field would produce a polar distortion, an electric field effect has rarely been considered when determining the OR angle. In this regard, the discovery of hybrid improper ferroelectricity (HIF) was a surprise because it shows an unexpected coupling between OR and ferroelectric (polar) distortion of Ca atom (A-atom in $\text{A}_3\text{B}_2\text{O}_7$) in double-layer perovskites such as $\text{Ca}_3\text{Ti}_2\text{O}_7$ (refs. 29,30). Some theoretical studies have proposed electrical control of physical properties by changing the OR angle via the HIF mechanism^{31,32}, but this has not yet been achieved experimentally. Contrary to the case of HIF, Sr_2RuO_4 is a metal and normally is not a suitable candidate for ferroelectric distortion. However, a finite displacement for Sr atom (A-atom in A_2BO_4) in the surface Sr_2RuO_4 layer can be induced by the surface electric potential, and then the Sr displacement may establish the connection between electric field and OR (Fig. 4). Note that A-atom mediates electric field and OR in both HIF and surface Sr_2RuO_4 cases, which may imply a possible universal mechanism of OR angle variation via A-atom modulation. Our work not only is to show a change in OR angle via electric field, but also may initiate follow-up studies to elucidate the mechanism of OR angle variation.

Finally, let us discuss possible effects of OR angle variation in systems with strong electron correlation since perovskite oxides are typically in the strong electron correlation regime. Since OR angle can significantly affect the exchange interaction as well as electron localization, it is expected that change in the OR angle can lead to various phenomena, e.g., magnetism and metal–insulator transitions. Such effects may be found in the case of $\text{Ca}_{2-x}\text{Sr}_x\text{RuO}_4$ (CSRO) which may be viewed as Sr_2RuO_4 with OR angle variation. In CSRO, rich and complex phases^{33–35}, such as magnetisms (ferromagnetism³³ or antiferromagnetism³⁴), appear and emergence of those phenomena are attributed to OR distortions^{5,36,37}. Another important aspect is that the electronic structure of Sr_2RuO_4 possesses a van Hove singularity near the Fermi level whose position is very sensitive to the OR angle. The large density of states from the van Hove singularity can

boost the instability from electron correlation. This implies that we could effectively control the electron correlation strength of the system via the OR angle. Control of OR therefore may allow us a more diverse controllability of physical properties in strongly correlated materials.

In conclusion, our experimental and theoretical investigations demonstrate that variation of electric potential is responsible for the OR angle in the Sr_2RuO_4 surface layer, and that OR angle can be varied by tuning the electric potential through surface K dosing. Our result not only sheds light on the mechanism of octahedral distortion found in various oxide systems but is also an important step toward electric field control of physical properties via variation of the OR angle in perovskite oxides.

METHODS

ARPES and LEED measurement conditions

ARPES ($h\nu = 70$ eV) measurements were performed at beam lines (BLs) 4.0.3 and 7.0.2 of the Advanced Light Source, Lawrence Berkeley National Laboratory, USA. Potassium dosing was carried out by evaporating K onto the sample using commercial alkali metal dispensers (SAES). Spectra were acquired with R8000 (BL 4.0.3) and R4000 (BL 7.0.2) electron analyzers (Scienta). Total energy resolution was set to 12 meV, and the angular resolution was 0.00163 \AA^{-1} . Cleaving and dosing of the samples were done at 20 K in an ultra-high vacuum better than 5×10^{-11} Torr. LEED measurements were performed at BL 7.0.2 of the Advanced Light Source and at the Center for Correlated Electron Systems of the Institute for Basic Science, Seoul National University, Republic of Korea, using a LEED spectrometer (SPECS) with an electron energy of 187 eV.

Information of DFT calculation

As the feasibility of using DFT to understand the structural and electronic properties of Sr_2RuO_4 has been shown through previous studies^{15,16,22}, we performed first-principle calculation using the non-spin-polarized DFT method without spin-orbit coupling. The Perdew–Burke–Ernzerhof form of the exchange–correlation functional was used as implemented in VASP software^{38,39}. We used a 600 eV plane wave cut-off energy and $12 \times 12 \times 1$ k -points for all calculations and the projector augmented wave method. The in-plane lattice constant was fixed at the experimental value of Sr_2RuO_4 . All the internal atomic positions were fully relaxed until the maximum force was below 0.5 meV \AA^{-1} while the symmetries of the system (point group D_{4h}) were maintained during the relaxation. In practice, since full relaxation is numerically unstable, we fixed the rotation angle of the octahedron and relaxed only the vertical positions of the atoms of the surface. In this way, the energy curve as a function rotation angle was obtained, and the angle with the energy minimum was found. We also checked that no additional symmetry lowering occurs even without symmetry constraints for a few cases. To mimic partial K coverage, we performed a five-layer slab calculation with 15 \AA vacuum layer, which is symmetric with respect to the middle layer with an overlying K atom layer. In this calculation, we relaxed the distance between the K layer and the Sr_2RuO_4 to find the equilibrium K-layer position. The resultant value was the ‘K EQ position’ in Fig. 3 (9.4 \AA^{-1} from the second Ru–O layer). In the calculation, we relaxed both the outermost layer and the K-layer distance, which explains why we defined the position relative to the second Ru–O layer. The location of each K atom could not be specified experimentally, so we assumed it to be above the apical oxygen atom of the outermost Sr–O layer (as illustrated in Fig. 3a) since that is the energetically most stable position in our DFT calculation. For the bulk calculations of Sr_2RhO_4 and Sr_2IrO_4 , the in-plane lattice constants were also fixed as the experimental lattice constant of each compound, 5.4516 and 5.4956 Å , respectively. In these calculations, we fixed the Sr and Ir positions and allowed to move oxygen atoms only to find the optimum rotation angle of the octahedron for a given Sr–Sr distance.

DATA AVAILABILITY

The datasets generated during and/or analyzed during the current study are available from the corresponding author upon request.

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AUTHOR CONTRIBUTIONS

W.K. conceived the work. W.K., Y.K.K., B.K., and C.K. (Chul Kim) performed ARPES measurements with the support from J.D.D., and W.K. and Y.K.K. analyzed the data. W.K., W.J., J.K., and M.K. performed the LEED measurement with support from A.B. Samples were grown and characterized by Y.Y.. C.H.K. led the theoretical study and performed the DFT calculation. All authors discussed the results. W.K. and C.K. (Changyoung Kim) led the project and manuscript preparation with contributions from all authors.

COMPETING INTERESTS

The authors declare no competing interests.

ADDITIONAL INFORMATION

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